8 T V_{CC+}

7 DY

5 🕇 RA

6 RTC

D OR P PACKAGE TOP VIEW

 V_{CC}

DA [

RY **∏**

GND [

3

SLLS017C - JULY 1986 - REVISED MAY 1995

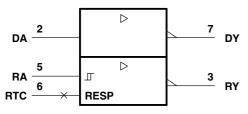
- Meets or Exceeds the Requirements of ANSI EIA/TIA-232-E and ITU Recommendation V.28
- 10-mA Current Limited Output
- Wide Range of Supply Voltage
 V_{CC} = 4.5 V to 15 V
- Low Power . . . 130 mW
- Built-In 5-V Regulator
- Response Control Provides: Input Threshold Shifting Input Noise Filtering
- Power-Off Output Resistance . . . 300 Ω Typ
- Driver Input TTL Compatible

description

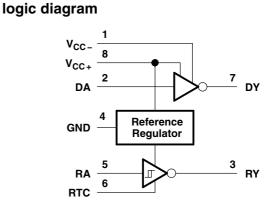
The SN75155 monolithic line driver and receiver is designed to satisfy the requirements of the standard interface between data terminal equipment and data communication equipment as defined by ANSI EIA/TIA-232-E. A response control input is provided for the receiver. A resistor or a resistor and a bias voltage can be connected between the response control input and ground to provide noise filtering. The driver used is similar to the SN75188. The receiver used is similar to the SN75189A.

The SN75155 is characterized for operation from 0°C to 70°C.

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12

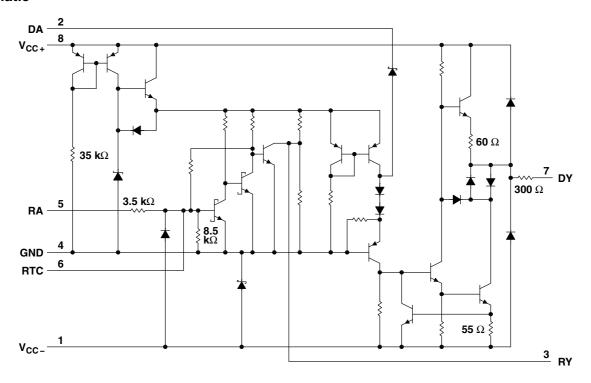




Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



schematic



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC+} (see Note 1)	15 V
Supply voltage, V _{CC} (see Note 1)	
Input voltage range, V _I : Driver	–15 V to 15 V
Receiver	–30 V to 30 V
Output voltage range (driver), V _O	–15 V to 15 V
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{sta}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW
Р	1000 mW	8.0 mW/°C	640 mW



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recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC+}	4.5	12	15	V
Supply voltage, V _{CC} _	-4.5	-12	-15	V
Output voltage, driver, V _{O(D)}			±15	V
Input voltage, receiver, V _{I(R)}	-25		25	V
High-level input voltage, driver, V _{IH}	2			٧
Low-level input voltage, driver, V _{IL}			8.0	V
Response control current			±5.5	mA
Output current, receiver, I _{O(R)}			24	mA
Operating free-air temperature, T _A	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

total device

	PARAMETER		TEST CONDITION	NS	MIN	TYP [†]	MAX	UNIT
		$V_{CC+} = 5 V$,	$V_{CC} = -5 \text{ V}$	$V_{I(D)} = 2 V,$		6.3	8.1	
I _{CCH+}	High-level supply current	$V_{CC+} = 9 V$,	$V_{CC} = -9 \text{ V}$	$V_{I(R)} = 2.3 V,$		9.1	11.9	mA
		$V_{CC+} = 12 \text{ V},$	$V_{CC-} = -12 \text{ V}$	Output open		10.4	14	
		$V_{CC+} = 5 V$,	$V_{CC-} = -5 \text{ V}$	$V_{I(D)} = 0.8 \text{ V},$		2.5	3.4	
I _{CCL+}	Low-level supply current	$V_{CC+} = 9 V$,	$V_{CC-} = -9 V$	$V_{I(R)} = 0.6 \text{ V},$		3.7	5.1	mA
		$V_{CC+} = 12V$,	$V_{CC-} = -12 \text{ V}$	Output open		4.1	5.6	
	Committee	$V_{CC+} = 5 V$,	V _{CC} – = 0	V _{I(R)} = 2.3 V,		4.8	6.4	mA
I _{CC+}	Supply current	$V_{CC+} = 9 V$,	V _{CC} – = 0	$V_{I(D)} = 0$		6.7	9.1	
		$V_{CC+} = 5 V$,	$V_{CC} = -5 \text{ V}$	V _{I(D)} = 2 V,		-2.4	-3.1	
I _{CCH} _	High-level supply current	$V_{CC+} = 9 V$,	$V_{CC} = -9 \text{ V}$	$V_{I(R)} = 2.3 \text{ V}$		-3.9	-4.9	mA
		$V_{CC+} = 12 \text{ V},$	$V_{CC-} = -12 \text{ V}$	Output open		-4.8	-6.1	
		$V_{CC+} = 5 V$,	$V_{CC} = -5 \text{ V}$	$V_{I(D)} = 0.8 \text{ V},$		-0.2	-0.35	
I _{CCL} _	Low-level supply current	$V_{CC+} = 9 V$,	$V_{CC} = -9 V$	$V_{I(R)} = 0.6 \text{ V},$		-0.25	-0.4	I mA
		$V_{CC+} = 12 \text{ V},$	$V_{CC-} = -12 \text{ V}$	Output open		-0.27	-0.45	

[†] All typical values are at $T_A = 25$ °C.

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electrical characteristics over recommended operating free-air temperature range, V_{CC+} = 12 V, $V_{CC-} = -12 \text{ V (unless otherwise noted)}$

driver section

	PARAMETER		TES	CONDITIONS		MIN	TYP†	MAX	UNIT
				$V_{CC+} = 5 V$,	$V_{CC-} = -5 \text{ V}$	3.2	3.7		
V_{OH}	High-level output voltage	$V_{IL} = 0.8 V,$	$R_L = 3 \text{ k}\Omega$	$V_{CC+} = 9 V$,	$V_{CC-} = -9 V$	6.5	7.2		V
				$V_{CC+} = 12 \text{ V},$	$V_{CC-} = -12 \text{ V}$	8.9	9.8		
				$V_{CC+} = 5 V$,	$V_{CC} = -5 \text{ V}$		-3.6	-3.2	
V _{OL}	Low-level output voltage (see Note 2)	V _{IH} = 2 V,	$R_L = 3 \text{ k}\Omega$	$V_{CC+} = 9 V$,	$V_{CC} = -9 \text{ V}$		-7.1	-6.4	V
				$V_{CC+} = 12 \text{ V},$	$V_{CC-} = -12 \text{ V}$		-9.7	-8.8	
I _{IH}	High-level input current	$V_I = 7 V$						5	μΑ
I_{IL}	Low-level input current	$V_I = 0$					-0.73	-1.2	mA
I _{OS(H)}	High-level short-circuit output current	$V_{I} = 0.8 V,$	V _O = 0			-7	-12	-14.5	mA
I _{OS(L)}	Low-level short-circuit output current	V _I = 2 V,	V _O = 0			6.5	11.5	15	mA
r _O	Output resistance with power off	$V_O = -2 \text{ V to}$	2 V				300		Ω

receiver section (see Figure 1)

	PARAMETER		TEST CONDITION	ONS	MIN	TYP†	MAX	UNIT
V_{IT+}	Positive-going input threshhold voltage				1.2	1.9	2.3	V
V _{IT} _	Negative-going input threshhold voltage				0.6	0.95	1.2	٧
V _{hys}	Hystresis voltage (V _{IT+} – V _{IT-})				0.6			V
		$V_1 = 0.6 V$,	$V_{CC+} = 5 V$,	$V_{CC-} = -5 \text{ V}$	3.7	4.1	4.5	
l.,	High-level output voltage	$I_{OH} = 10 \mu A$	$V_{CC+} = 12 \text{ V},$	$V_{CC-} = -12 \text{ V}$	4.4	4.7	5.2	V
V _{O(H)}		$V_1 = 0.6 V$	$V_{CC+} = 5 V$,	$V_{CC} = -5 \text{ V}$	3.1	3.4	3.8	V
		$I_{OH} = 0.4 \text{ mA}$	$V_{CC+} = 12 \text{ V},$	$V_{CC-} = -12 \text{ V}$	3.6	4	4.5	
$V_{O(L)}$	Low-level output voltage	$V_1 = 2.3 V$,	$I_{OL} = 24 \text{ mA}$			0.2	0.3	V
	Little Level Search comment	V _I = 2 5 V			3.6	6.7	10	mA
1 _{IH}	High-level input current	V _I = 3 V			0.43	0.67	1	mA
	Laure Investigation of the second	$V_1 = -25 \text{ V}$			-3.6	-6.7	-10	mA
I _{IL}	Low-level input current	$V_{I} = -3 V$			-0.43	-0.67	-1	mA
Ios	Short-circuit output current	$V_1 = 0.6 V$				-2.8	-3.7	mA

[†] All typical values are at $T_A = 25$ °C.

NOTE 2: The algebraic limit system, in which the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic voltage levels only (e.g., if –8.8 V is the maximum, the typical value is a more negative value).



switching characteristics over recommended operating free-air temperature range, V_{CC+} = 5 V, V_{CC-} = -5 V, C_L = 50 pF (unless otherwise noted)

driver section (see Figure 2)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high level output	B alo		250	480	
t _{PHL}	Propagation delay time, high- to low level output	$R_L = 3 \text{ k}\Omega$		80	150	ns
	Outrot diag time	$R_L = 3 \text{ k}\Omega$		67	180	ns
ι _r	Output rise time	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega, \qquad C_L = 2500 \text{ pF}$		2.4	3	μs
	Output fall time	$R_L = 3 \text{ k}\Omega$		48	160	ns
Ч	Output fair time	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega, \qquad C_L = 2500 \text{ pF}$		1.9	3	μs

receiver section (see Figure 3)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high level output	B 400 C		175	245	
t _{PHL}	Propagation delay time, high- to low level output	$R_L = 400 \Omega$		37	100	ns
t _r	Output rise time	$R_L = 400 \Omega$		255	360	ns
t _f	Output fall time	$R_L = 400 \Omega$		23	50	ns

[†] All typical values are at $T_A = 25$ °C.

PARAMETER MEASUREMENT INFORMATION

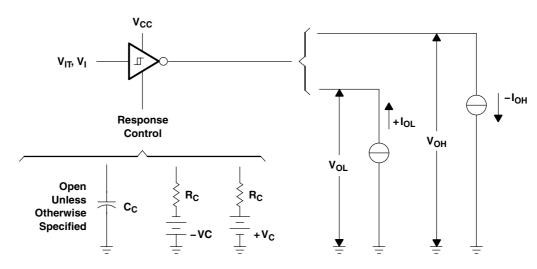
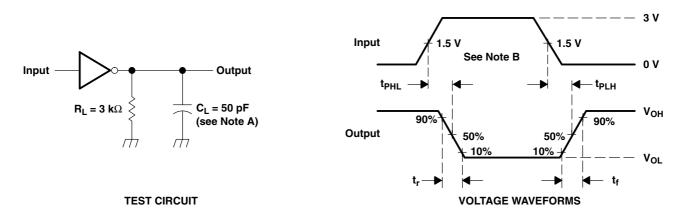


Figure 1. Receiver Section Test Circuit (V_{IT+} , V_{IT-} , V_{OH} , V_{OL})

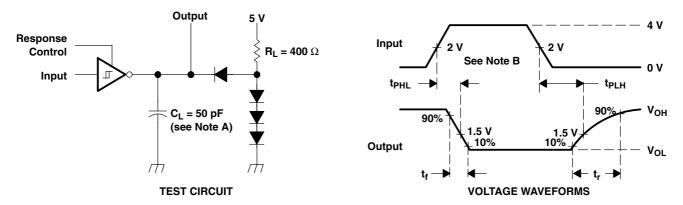
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. The input waveform is supplied by a generator with the following characteristics: $Z_O = 50 \ \Omega$, $t_W = 1 \ \mu s$, $t_f \le 10 \ ns$.

Figure 2. Driver Section Switching Test Circuit and Voltage Waveforms

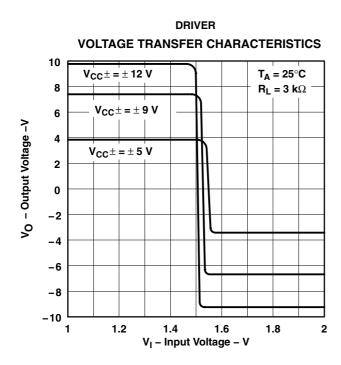


NOTES: A. C_L includes probe and jig capacitance.

B. The input waveform is supplied by a generator with the following characteristics: $Z_Q = 50 \Omega$, $t_W = 1 \mu s$, $t_f \le 10 ns$, $t_f \le 10 ns$.

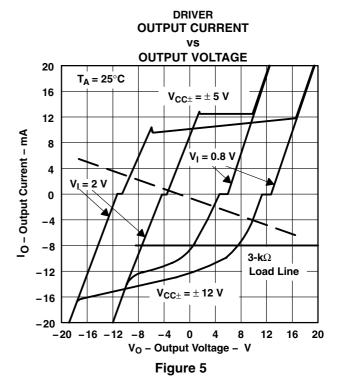
Figure 3. Receiver Section Switching Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS





DRIVER



DRIVER SLEW RATE vs

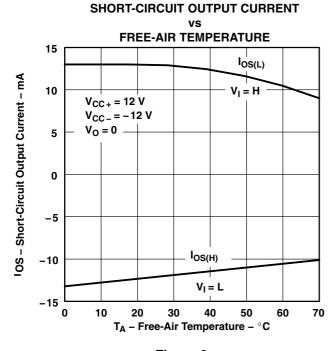


Figure 6

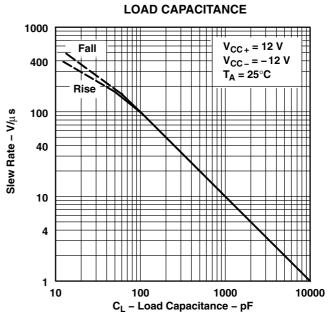


Figure 7

TYPICAL CHARACTERISTICS

RECEIVER OUTPUT VOLTAGE

INPUT VOLTAGE

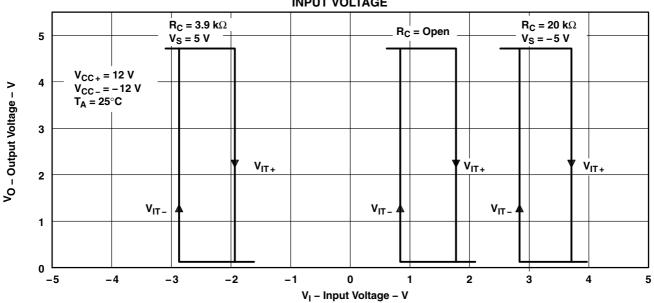


Figure 8

RECEIVER OUTPUT VOLTAGE

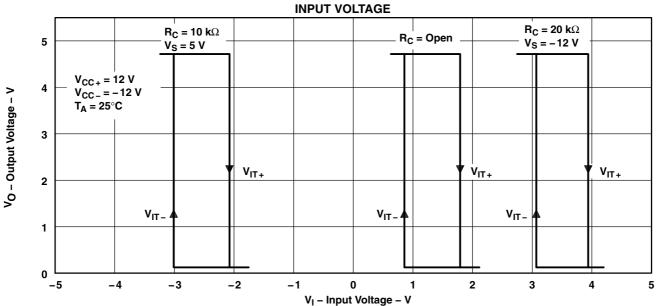
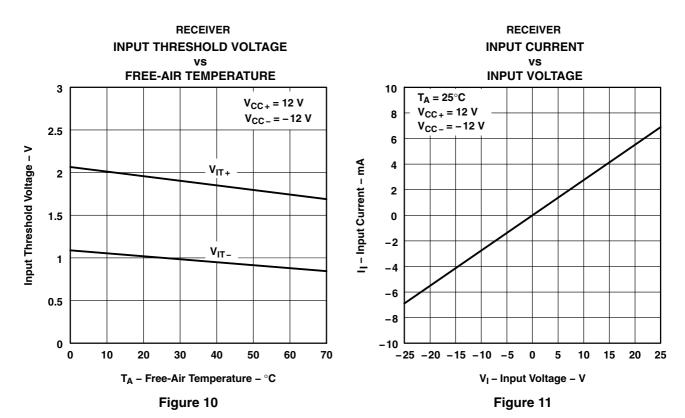


Figure 9



TYPICAL CHARACTERISTICS



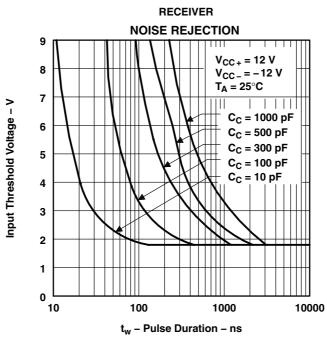




Figure 12





10-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN75155D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75155	Samples
SN75155DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75155	Samples
SN75155DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75155	Samples
SN75155DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75155	Samples
SN75155DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75155	Samples
SN75155P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75155P	Samples
SN75155PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75155P	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



PACKAGE OPTION ADDENDUM

10-Jun-2014

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

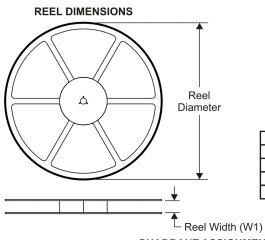
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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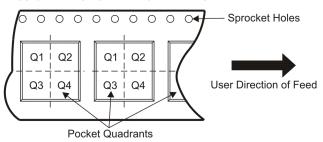
TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

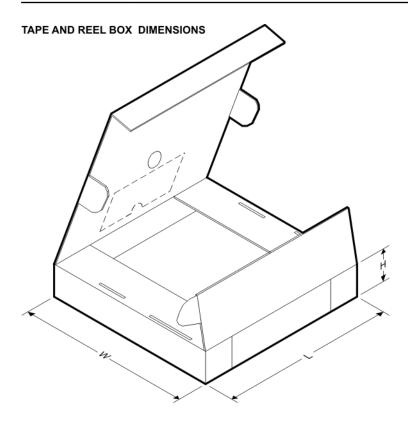
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

D	evice		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN7	75155DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



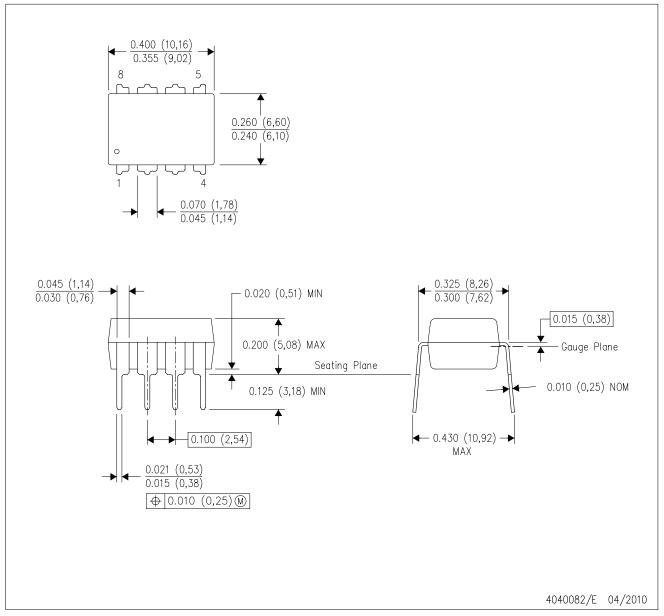


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75155DR	SOIC	D	8	2500	340.5	338.1	20.6

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



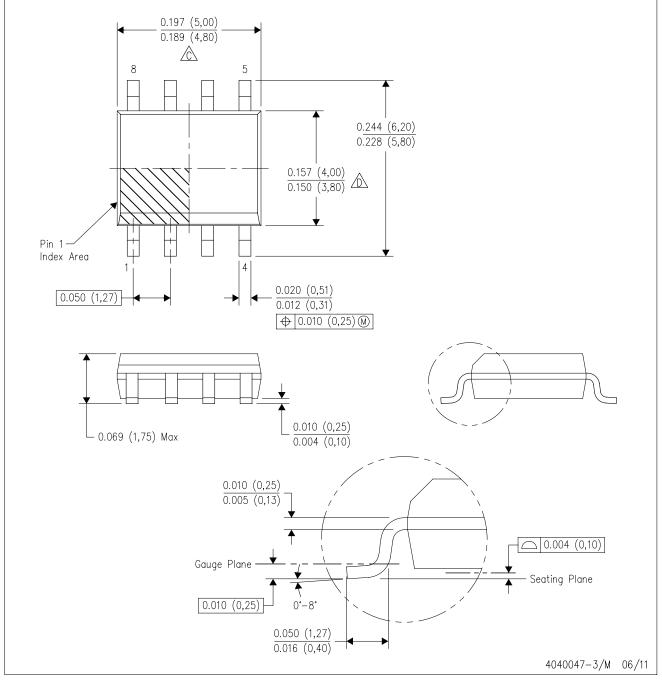
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



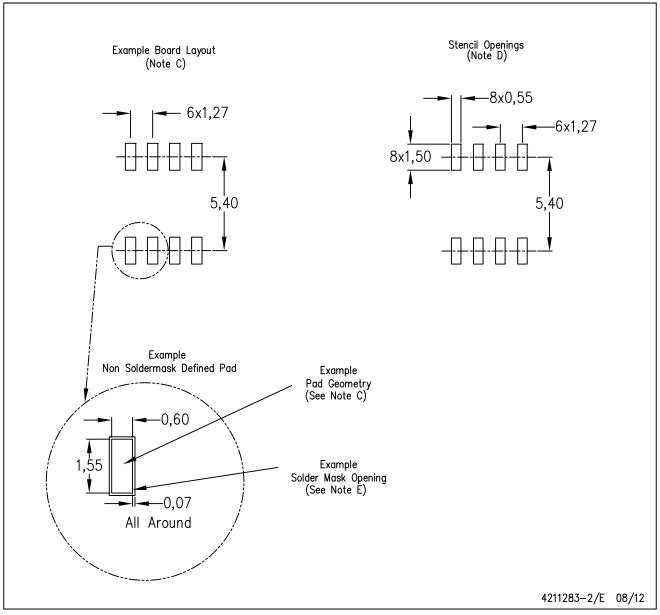
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

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